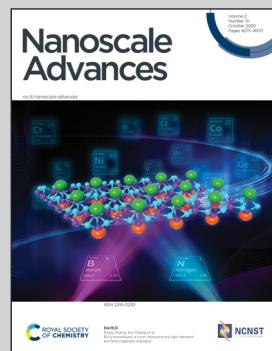


Showcasing research from the laboratories of Professors Jianbo Gao, Hugo Sanabria and Apparao Rao, Department of Physics and Astronomy, Clemson University, Clemson, SC 29634, USA.

The correlation between phase transition and photoluminescence properties of CsPbX_3 ($\text{X} = \text{Cl, Br, I}$) perovskite nanocrystals

Perovskite nanocrystals (NCs) have aroused tremendous interests in optoelectronic applications due to their high quantum yield and carrier mobility. In this work, the correlation between the structural phase transition and emissive properties of all-inorganic perovskite CsPbX_3 ($\text{X} = \text{Cl, Br, and I}$) NCs was investigated using steady-state photoluminescence (PL) and time resolved PL spectroscopies. A correlation between the electronic structure and exciton dynamics with the structural phase transition of CsPbX_3 was uncovered. This work provides a deeper insight into the role of phase-transition on the photo-physics of perovskite materials.

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We report a correlation between the structural phase transition of CsPbX_3 ($\text{X} = \text{Cl, Br, I}$) nanocrystals (NCs) and their temperature-dependent steady-state photoluminescence (PL) and time-resolved PL (TRPL). In contrast to CsPbBr_3 and CsPbI_3 NCs which exhibited a continuous blue-shift in their band gap with increasing temperature, the CsPbCl_3 exhibited a blue shift until ~ 193 K, followed by a red shift until room temperature. We attribute this change from a blue to a red shift to a structural phase transition in CsPbCl_3 , which also manifested in the temperature dependent TRPL. This pronounced phase transition in CsPbCl_3 NCs is probably due to the condensation of its vibrational modes at low temperature, and the presence of the weak quantum confinement effect. Notably, the exciton recombination lifetimes showed a similar reverse trend due to the phase transition in CsPbCl_3 , which has not been reported previously.

A phase transition is one of the most fundamental physical phenomena in solid-state physics as it could also influence the electrical, optical, magnetic, mechanical, and chemical properties of the materials. It is particularly important for emerging perovskite semiconductors, which have attracted much attention due to their superior electronic and optical properties. Bulk perovskite semiconductors are used in myriad applications such as light-emitted diodes (LED),¹ photovoltaics,²⁻⁴ X-ray detectors, lasers, and other optoelectronic devices^{5,6} because of their highly mobile free charge carriers,⁷⁻⁹ high absorption coefficients,^{10,11} low exciton binding energies,^{12,13} and long charge-carrier diffusion lengths.¹⁴ Not surprisingly, the

perovskite nanocrystals (NCs) are also attracting much attention because of their unique tunable optical properties, which stem from their size, structure, shape, and tunable compositions.¹⁵⁻¹⁷ Notably, perovskite NCs offer more stable phases, which are not achievable in the bulk materials. For instance, cubic phase α - CsPbI_3 NC-based solar cells exhibit more than 15% power conversion efficiency under ambient conditions and are stable for more than 100 hours, while the bulk CsPbI_3 is an unstable semiconductor under ambient conditions.¹⁸ Traditionally, phase transitions are widely characterized using X-ray diffraction (XRD) to provide detailed information of the lattice structure, which in turn could depend on temperature, pressure, light, electric field, etc. For instance, in bulk and nanocrystalline perovskite materials, temperature-dependent XRD has been used to investigate the phase transitions;^{19,20} however, there are only a few reports that correlate the phase transition with optical properties, which is of important for their applications in optoelectronics.

In this report, we investigate the temperature-dependent PL of all-inorganic perovskite CsPbX_3 ($\text{X} = \text{Cl, Br, and I}$) NCs using steady-state PL and time-resolved PL (TRPL) spectroscopies to correlate their phase transition with their emission properties. We found that the band gap energies and lifetimes increase continuously with the temperature in CsPbBr_3 and CsPbI_3 NCs; however, CsPbCl_3 NCs exhibited a blue shift until their phase transition temperature of ~ 193 K, followed by a red-shift until room temperature. Also, the lifetimes of CsPbCl_3 NCs decreased up to their phase transition temperature, above which they showed an increasing trend.

All-inorganic perovskite CsPbX_3 NCs were synthesized using a hot-injection method (see Experimental section).²¹ The cubic lattice framework of CsPbX_3 consists of the corner-sharing PbX_6 octahedra with Cs^+ embedded in the interstitial voids (Fig. 1a). The room temperature PL and absorption spectra of CsPbX_3 NC dispersions in hexane are shown in Fig. 1b, and the energy difference between the excitonic absorption peak and PL peak (or Stokes shift, which stems from the exciton relaxation processes) is evident.²² From detailed transmission

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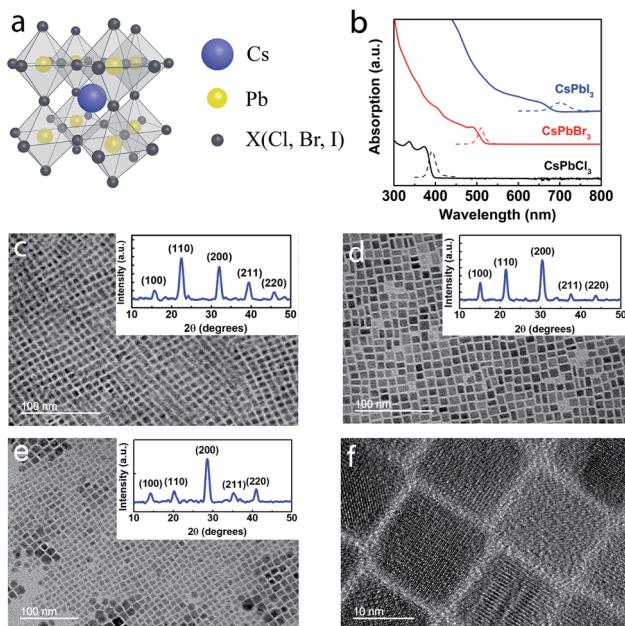


Fig. 1 Structural characterization of CsPbX_3 nanocrystals (NCs). (a) A schematic crystal structure of a cubic CsPbX_3 perovskite. (b) Room temperature absorption (solid) and PL spectra (dashed) of CsPbX_3 NCs in a hexane solution. TEM images of (c) CsPbCl_3 , (d) CsPbBr_3 , and (e) CsPbI_3 NCs. (f) High-resolution TEM image of CsPbI_3 NCs. The insets in panels (c–e) are the corresponding room temperature XRD patterns.

electron microscopy (TEM) analyses, the average NC size was found to be ~ 7.2 , ~ 9.1 , and ~ 14.9 nm for CsPbCl_3 , CsPbBr_3 , and CsPbI_3 , respectively (Fig. 1c–e). Fig. 1f shows the high-resolution TEM image of CsPbI_3 NCs. The Bohr radii of CsPbCl_3 , CsPbBr_3 , and CsPbI_3 are known to be ~ 5 , ~ 7 , and ~ 12

nm,²³ respectively, and the NCs exhibit weak quantum confinement since the ratio of NC size to the respective Bohr radius is ~ 1.24 to ~ 1.44 . It is well-known that organo-lead halide perovskites have three phases which include the high temperature cubic phase (>315 K), room temperature tetragonal phase (160–330 K) and low temperature orthorhombic phase (<160 K). The room temperature XRD patterns of the CsPbX_3 ($X = \text{Cl}, \text{Br}, \text{I}$) NCs used in this study are shown as insets in Fig. 1c–e. The CsPbI_3 NCs exhibit the cubic phase²⁴ with peaks at $2\theta = 14.2, 20.2, 28.6, 35.3$, and 41.0° corresponding to diffractions from the (100), (110), (200), (211) and (220) planes, and a shift in the diffraction peaks towards a higher angle (2θ) as X changes from I to Cl is ascribed to the lattice contraction caused by the shrinking size of the halide ion from I^- to Cl^- .²³ The XRD data confirmed the formation of CsPbX_3 quantum dots with the space group $Pm\bar{3}m$.²⁵

For the temperature-dependent studies, thin film samples of CsPbX_3 NCs were prepared by drop-casting the respective dispersions on quartz slides, and their temperature-dependent PL data were acquired (Fig. 2a–c). The excitation energies (wavelengths) used in this study for CsPbCl_3 , CsPbBr_3 , and CsPbI_3 NCs were 4.13 eV (300 nm), 3.54 eV (350 nm), and 2.48 eV (500 nm), respectively. It is evident that the PL intensity decreases in all three panels (a–c) with increasing temperature, which is due to the presence of increased non-radiative processes at high temperature. Furthermore, the PL emission peaks of CsPbBr_3 and CsPbI_3 NCs exhibit a blue shift with increasing temperature, which is in contrast to the temperature-dependent shift in the PL emission peak of CsPbCl_3 NCs (dashed arrows in Fig. 1a–c). As expected, a thermal broadening of the full-width-at-half-maximum (FWHM) intensity is also observed with increasing temperature in Fig. 2d–f. Using

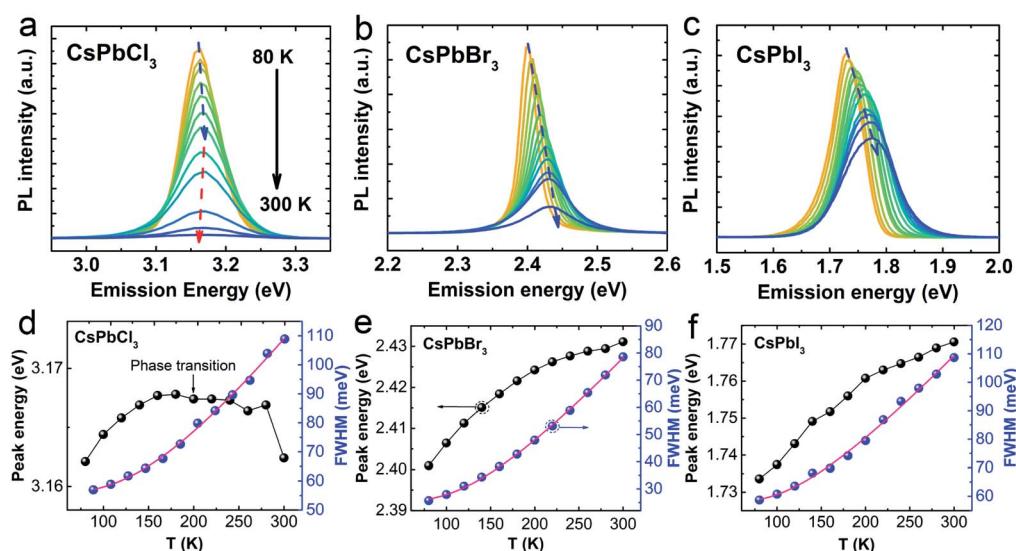


Fig. 2 Steady-state PL characteristics of CsPbX_3 NCs. Steady-state PL spectra of (a) CsPbCl_3 , (b) CsPbBr_3 , and (c) CsPbI_3 NCs in the temperature range of 80 K–300 K. Temperature-dependent full-width-at-half-maximum (FWHM) intensities and the emission peak energies of (d) CsPbCl_3 , (e) CsPbBr_3 , and (f) CsPbI_3 NCs. Blue and red dashed arrows in (a–c) show the blue and red shift of emission peak energy with the increasing temperature. The red traces in (d–f) represent least square fits to the temperature dependent FWHM data and the black traces serve as a guide to the eye.

different excitation energies, examples of low temperature 2D PL contour maps of CsPbBr_3 NCs are shown in Fig. S1 (see the ESI†) to demonstrate that the shift is independent of excitation energy.

The temperature-dependent band gap of perovskites reveals an unusual trend compared to traditional semiconductors. The band gaps of CsPbBr_3 and CsPbI_3 exhibited a blue shift with increasing temperature, which is in contrast to that predicted by the Varshni's empirical model in which electron-phonon coupling usually dominates and leads to a red shift of the band gap with increasing temperature.²⁶ A blue shift in the band gap energy can arise from an interplay of contributions from the lattice thermal expansion and electron-phonon coupling.^{27,28} The lattice thermal expansion has been reported to dominate and decrease the interaction between the orbitals in the valence band maximum (s orbital of Cs and p orbital of X), which leads to a decrease in the valence bandwidth and an increase in the band gap.^{27,29} Similar to CsPbBr_3 and CsPbI_3 , the band gap of CsPbCl_3 exhibited a blue shift in the 80–180 K temperature range. However, it showed a red shift in the temperature range from 200–300 K, which implies that the electron-phonon coupling dominates in CsPbCl_3 at higher temperatures. This change from a blue to a red shift is attributed to the low temperature phase transition ~ 193 K in CsPbCl_3 which is unique to CsPbCl_3 , and absent in CsPbBr_3 and CsPbI_3 . At ~ 193 K, CsPbCl_3 deviated from its centrosymmetric structure, which was confirmed by electron paramagnetic resonance, X-ray diffraction, photoacoustic and Raman spectroscopies.^{30–33} The low-temperature Raman spectroscopy of CsPbCl_3 revealed a unique change in the behavior of its vibration modes. The Raman modes located at 76 cm^{-1} , 95 cm^{-1} , 123 cm^{-1} and $<50\text{ cm}^{-1}$ start to disappear as the temperature increases above 193 K, which has been referred to as the condensation of these vibration modes in CsPbCl_3 at 193 K.³⁴ When the temperature decreases below 193 K, the structural phase of CsPbCl_3 changes from orthorhombic to monoclinic,³⁰ which was reported in CsPbCl_3 bulk materials.^{30–34} However, this phase transition is not exhibited by CsPbCl_3 quantum dots because of the strong quantum confinement condition,³⁵ but is exhibited by CsPbCl_3 NCs used in this study due to their weak quantum confinement condition.

To gain a deeper understanding of the mechanism, the temperature-dependent band gap and spectral broadening of PL for CsPbX_3 NCs are shown in Fig. 2d–f. The broadening with temperature is mainly due to the electron-phonon coupling which includes electron-acoustic phonon and electron-longitudinal optical (LO) phonon coupling.²⁹ In most semiconductors, the electron-LO phonon interaction dominates at temperatures above 80 K, thus neglecting the electron-acoustic phonon coupling; the broadening of PL linewidth can be expressed as³⁶

$$\Gamma(T) = \Gamma_0 + \gamma_{\text{LO}} \left/ \left(e^{\frac{E_{\text{LO}}}{k_B T}} - 1 \right) \right. \quad (1)$$

where, Γ_0 represents the inhomogeneously broadened linewidth due to scattering by disorder and imperfections in the NCs. The second term represents homogeneous broadening

Table 1 Extracted linewidth parameters of CsPbX_3 NCs

Sample	Γ_0 (meV)	γ_{LO} (meV)	E_{LO} (meV)
CsPbCl_3	56.5 ± 0.82	176.2 ± 22.75	38.0 ± 2.69
CsPbBr_3	25.4 ± 0.38	160.4 ± 9.27	36.1 ± 1.18
CsPbI_3	57.8 ± 1.11	139.1 ± 23.18	33.8 ± 3.33

which results from scattering of LO phonons (Fröhlich interaction) with an energy E_{LO} and electron-phonon coupling strength of γ_{LO} , and k_B is the Boltzmann constant. The least-square fits to the linewidth of emission peaks are shown as the red traces in Fig. 2d–f, and the extracted parameters are listed in Table 1. In particular, the E_{LO} value increases from 33.8 meV for heavy iodine anions to 38.0 meV for lighter chloride anions. Furthermore, the γ_{LO} is highest in CsPbCl_3 , followed by that of CsPbBr_3 and CsPbI_3 , which is due to the lower high-frequency values of the dielectric function of CsPbCl_3 and CsPbBr_3 .³⁷ For CsPbX_3 , the displacement of Pb atoms dominates the acoustic mode vibrations, while the displacement of halogen anions dominates optical mode vibrations.³⁸ Thus, the E_{LO} of the CsPbX_3 scales with the halogen anion mass, namely, the lighter halogen anions exhibit higher vibration frequency resulting in a higher E_{LO} . In addition, by fitting the temperature-dependent PL intensity using the Arrhenius equation,^{29,35} the binding energies of CsPbCl_3 , CsPbBr_3 , and CsPbI_3 NCs were obtained as 133.19 meV, 52.98 meV, and 60.18 meV, which are close to the values reported in previous studies.^{23,35} The difference is mainly due to the quantum confinement effect resulting from the different sizes of nanocrystals.

As mentioned, we attribute the unusual red shift with decreasing temperature and a common blue shift with increasing temperature to the phase transition in CsPbCl_3 NCs. This is also consistent with the temperature-dependent TRPL results as shown in Fig. 3, which can be manifested by the exciton decay dynamics. In general, TRPL data is analyzed in terms of single ($I = I_0 + A_1 \exp(-t/t_1)$) or bi-exponential ($I = I_0 + A_1 \exp(-t/t_1) + A_2 \exp(-t/t_2)$) decay processes, where I_0 represents the offset of normalized PL intensity, and (A_1, t_1) and, (A_2, t_2) are the relative weights and lifetimes, respectively. In the case of CsPbCl_3 , it exhibited a unique trend: in the 80–180 K (200–300 K) range, its lifetimes decrease (increase) with increasing temperature, and the phase transition temperature of 180 K is consistent with that induced from the steady-state PL. In contrast, in the case of CsPbBr_3 (single exponential process) and CsPbI_3 (bi-exponential process, see Table S1 in ESI†), their lifetimes increase with increasing temperature, which is consistent with the recently reported trends due to exciton fission.³⁵ Its increasing trend in the 200–300 K range was similar to that of CsPbBr_3 and CsPbI_3 . From 180 to 300 K, the structural phase of CsPbCl_3 is orthorhombic, which is the same as the structural phase of CsPbBr_3 and CsPbI_3 , hence the lifetime of CsPbCl_3 shows the same increasing trend as the lifetime of CsPbBr_3 and CsPbI_3 . However, for temperatures below 193 K, the structural phase of CsPbCl_3 changes from orthorhombic to monoclinic, leading to a reverse trend in the temperature-dependent lifetime. This novel finding clearly suggests that the



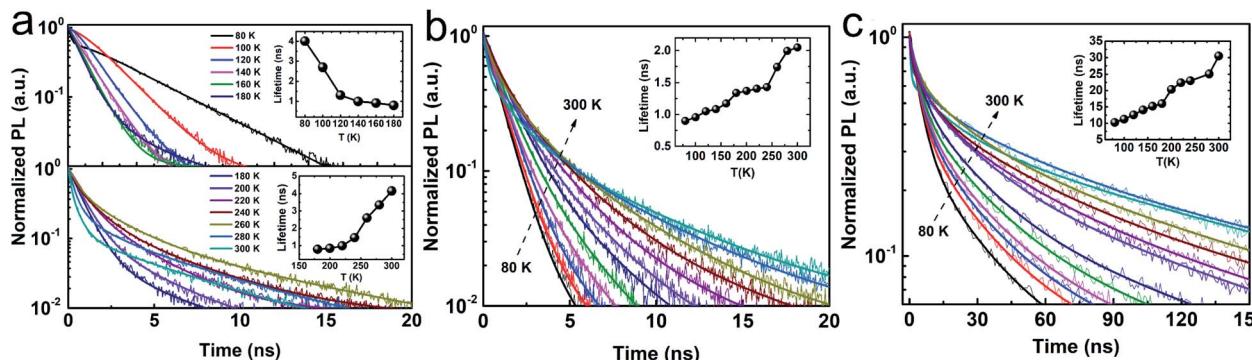


Fig. 3 TRPL characteristics of CsPbX_3 NCs. Normalized TRPL data of (a) CsPbCl_3 , (b) CsPbBr_3 , and (c) CsPbI_3 NCs in the temperature range from 80–300 K. Each colored trace in the figure represents TRPL data that were collected at a specific temperature (legends shown in panel (a)). The solid traces are fits to the data, and the insets show the corresponding lifetimes. For clarity, two sub-panels are shown in panel (a).

excitonic recombination lifetime is intimately coupled with the structural phase transition. Such phase transition induced trend reversal in the temperature-dependent band gap and lifetimes reveals the correlation between phase transition, electronic structure, and exciton dynamics, which can provide significant guidance for phase transition-related electronic and optical properties of the perovskite.

Conclusions

In summary, we investigated the temperature-dependent PL and TRPL of CsPbX_3 NCs in the 80 to 300 K temperature range, which revealed a correlation between phase transition, electronic structure, and exciton dynamics. In particular, the low temperature phase transition of CsPbCl_3 at ~ 193 K resulted in a reverse temperature dependence of band gap that red-shifted with increasing temperature until 300 K. Furthermore, the exciton recombination lifetimes showed the similar reverse trend due to the phase transition, which has not been reported previously. Overall, this study presents comprehensive temperature-dependent spectroscopic signatures of all-inorganic perovskites CsPbX_3 NCs, which provide a deeper insight into the effect of phase-transition on the low temperature photo-physics of perovskite materials.

Experimental

Synthesis and characterization

Chemicals. Cesium carbonate (Cs_2CO_3 , 99.9%), lead(II) acetate trihydrate ($\text{Pb}(\text{OAc})_2 \cdot 3\text{H}_2\text{O}$, 99.999%), benzoyl chloride (99%), benzoyl bromide (97%), iodotrimethylsilane (97%), oleic acid (OA, technical grade, 90%), oleylamine (OAm, technical grade, 70%), and 1-octadecene (ODE, technical grade, 90%) were purchased from Sigma-Aldrich. Toluene, hexanes, and ethyl acetate were purchased from Fisher Scientific. All chemicals were used as received without further purification.

Synthesis of CsPbX_3 ($\text{X} = \text{Cl, Br, and I}$) perovskite nanocrystals (NCs). CsPbX_3 ($\text{X} = \text{Cl, Br, I}$) NCs were synthesized using the hot-injection method following a modified process published in the literature.²⁶ In a typical synthesis, Cs_2CO_3 (32 mg,

0.2 mmol) and $\text{Pb}(\text{OAc})_2 \cdot 3\text{H}_2\text{O}$ (137 mg, 0.36 mmol) were mixed with OA (0.6 mL), OAm (2.0 mL) and ODE (10.0 mL) and then added to a 50 mL three-neck flask. The mixture was first degassed for 5 min at room temperature, and then for 1 hour when the temperature was increased to 120 °C. The mixture became transparent after all precursors dissolved well and then the flask was heated to 200 °C in a N_2 atmosphere (170 °C for CsPbBr_3 , and 165 °C for CsPbI_3). Upon reaching this temperature, 0.40 mL benzoyl chloride (0.30 mL benzoyl bromide for CsPbBr_3 , and 0.30 mL iodotrimethylsilane for CsPbI_3) was injected into the solution which immediately became turbid. After 10 s, the solution was cooled down to room temperature using an ice bath which resulted in a stable dispersion.

Purification. 15 mL of ethyl acetate was added to the above described dispersions and the mixtures were centrifuged for 10 min at 7000 rpm. The supernatant was discarded and the precipitate was dispersed in 10 mL toluene (or hexane). The dispersion was again centrifuged for 5 min at 4500 rpm to separate nanocrystals of larger sizes. The clear supernatant solution was kept for further characterization.

Characterization. UV-Vis absorption spectra were measured using an Agilent Technologies Cary 5000 UV-Vis spectrophotometer. CsPbX_3 ($\text{X} = \text{Cl, Br, and I}$) perovskite nanocrystals were dissolved in toluene for the measurements. TEM measurements were performed on a JEOL 2100F operated at 200 kV. CsPbX_3 ($\text{X} = \text{Cl, Br, and I}$) perovskite nanocrystals were diluted in toluene, then drop cast on a 300-mesh copper TEM grid and dried under ambient conditions. X-ray diffraction (XRD) patterns were obtained on a Bruker D8 Discovery 2D X-ray Diffractometer equipped with a Vantec 500 2D area detector operating with $\text{Cu K}\alpha$ ($\lambda = 1.541$ Å) radiation. The NC samples were drop-cast on the glass slides and evaporated under mild heating.

Temperature dependent steady-state PL and TRPL spectra

The temperature dependent PL experiments were performed using a modular spectrofluorometer system (HORIBA Nanolog) which consisted of a Xenon lamp (HORIBA FL-1039), an excitation monochromator, a sample-compartment module, an emission spectrometer and a CCD detector (HORIBA Symphony II). The TRPL spectra were measured by using



a spectrofluorometer (HORIBA FluoroLog FL3-22) equipped with a picosecond photon detection module (TBX-05) and a 375 nm laser source (NanoLED N-375L) controlled by using a single photon counting controller (FluoroHub). The dispersions of CsPbX_3 QDs were drop-casted onto quartz substrates and then placed inside an optical cryostat (JANIS, ST-100 equipped with a Turbolab 350) which was illuminated by using the Xenon lamp and laser. The temperature of the cryostat was controlled by using a temperature controller (Lake Shore, Model 325).

Conflicts of interest

The authors declare no conflict of interest.

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